

# SM806028

Flexible Ultra-Low Jitter Clock Generator

#### ClockWorks® FLEX

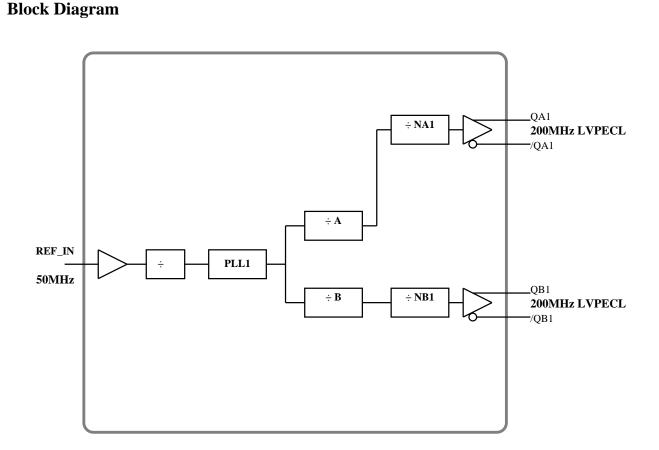
#### **General Description**

The SM806028 is a member of the ClockWorks® FLEX family of devices from Microchip and provides an extremely low-noise timing solution. It is based upon a unique PLL architecture that provides very-low phase noise.

The device operates from a 2.5V or 3.3V power supply.

#### Features

- Generates 2 output clocks
- Frequency and output logic:
  - 200MHz LVPECL x 2
- 50MHz Reference Input, DIFF
- Typical phase noise:
  - 78fs (Integration range: 12kHz-20MHz)
- On-chip power supply regulation for excellent board level power supply noise immunity
- No external crystal oscillator capacitors required
- 2.5V or 3.3V operating power supply
- Industrial temperature range
- 24-pin 4x4x.85mm VQFN



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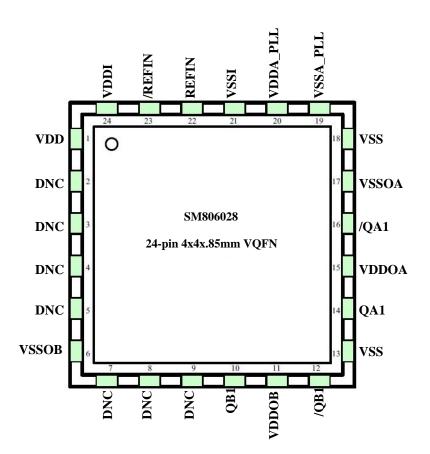
M9999-012120-A tcghelp@microchip.com

# **Ordering Information**

Ordering Part Number	Ordering Part Number Marking Shippi		Ambient Temperature Range	Package		
SM806028UMG	806028	Tube	-40°C to +85°C	24-pin 4x4x.85mm VQFN		
SM806028UMG TR	806028	Tape and Reel	-40°C to +85°C	24-pin 4x4x.85mm VQFN		

Devices are Green and RoHS compliant. Sample material may have only a partial top mark.

# **Pin Configuration**



# **Pin Description**

Pin Number	Pin Name	Pin Type	Pin Level	Pin Function
1	VDD	PWR		Power Supply
2, 4, 5	DNC			Do not connect anything to these pins
3	DNC			Do not connect
6	VSSOB	PWR		Ground Return Path for the Bank B Output Drivers
7	DNC			Do not connect
8	DNC			Do not connect
9	DNC			Do not connect
10, 12	QB1, /QB1	O, Diff	LVPECL	Clock Output QB1 Frequency = 200MHz
11	VDDOB	PWR		Power Supply for Outputs QB
13, 18	VSS	PWR		Power Supply Ground
14, 16	QA1, /QA1	O, Diff	LVPECL	Clock Output QA1 Frequency = 200MHz
15	VDDOA	PWR		Power Supply for Outputs QA
17	VSSOA	PWR		Ground Return Path for the Bank A Output Drivers
19	VSSA_PLL	PWR		Analog Power Return for PLL
20	VDDA_PLL	PWR		Analog Power Supply for PLL
21	VSSI	PWR		Ground for Reference Input Circuits and Crystal Oscillator
22, 23	REFIN, /REFIN	I, Diff	LVPECL LVDS HCSL	Reference Clock Input = 50MHz
24	VDDI	PWR		Power Supply for Reference Input Circuits and Crystal Oscillator

## Absolute Maximum Ratings<sup>1</sup>

Supply Voltage (VDD, VDDA, VDDI,	VDDO)+4.6V
Input Voltage (VIN)	-0.50V to +4.6V
ESD Machine Model	200V
ESD Human Body Model	2kV

## **Operating Ratings<sup>2</sup>**

Supply Voltage (VDD, VDDO)....+2.375V to +3.465V

### **Electrical Characteristics**

Typical values are TA =  $25^{\circ}$ C, min/max across  $-40^{\circ}$ C <= TA <=  $+85^{\circ}$ C, unless otherwise noted.

Symbol	Parameter	Condition	Min.	Тур.	Max.	Units
VDD, VDDO	Supply Voltage	2.5V Operation 3.3V Operation	2.375 3.135	2.5 3.3	2.625 3.465	V
VDDI	Analog & I/O Supply		2.375		3.465	V
VDDA	PLL Core		2.375		3.465	V
IDDA	PLL Core Current Consumption				60	mA
IDDI	Analog & I/O Current				20	mA
IDDO	Output Stage Current Consumption	Per output bank, unloaded			70	mA
IDD	SPI and Miscellaneous Logic				8	mA

#### **REF\_IN DC Electrical Characteristics**

VDD = 3.3V  $\pm 5\%$  or 2.5V  $\pm 5\%$ , TA = -40°C to  $+85^{\circ}C$ 

Symbol	Parameter	Condition	Min.	Тур.	Max.	Units
Vcmr	Input Common Mode Voltage		0.3		VDD - 0.3	V
Vswing	Input Voltage Swing		0.2			VPP

Notes:

1. Exceeding the absolute maximum ratings may damage the device.

2. The device is not guaranteed to function outside its operating ratings.

## **LVPECL DC Electrical Characteristics**

VDDcore= VDD = VDDO =  $3.3V \pm 5\%$  or  $2.5V \pm 5\%$ , TA =  $-40^{\circ}$ C to  $+85^{\circ}$ C, unless otherwise noted. RL = 50 Ohms to VDDO - 2V.

Symbol	Parameter	Condition	Min.	Тур.	Max.	Units
VOH	Output High Voltage	50 Ohms to VDDO - 2V	VDDO - 1.35	VDDO - 1.01	VDDO - 0.8	V
VOL	Output Low Voltage	50 Ohms to VDDO - 2V	VDDO - 2	VDDO - 1.78	VDDO - 1.6	V
Vswing	Peak-to-Peak Output Voltage	Figure "Duty Cycle Timing"	0.65	0.77	0.95	V

## **LVCMOS DC Electrical Characteristics**

VDDcore= VDD = VDDO =  $3.3V \pm 5\%$  or  $2.5V \pm 5\%$ , TA =  $-40^{\circ}$ C to  $+85^{\circ}$ C, unless otherwise noted. RL = 50 Ohms to VDDO/2.

Symbol	Parameter	Condition	Min.	Тур.	Max.	Units
VOH	Output High Voltage	Highest drive (default)	VDD - 0.8			V
VOL	Output Low Voltage				0.5	V
VIH	Input High Voltage		VDD - 0.7		VDD + 0.3	V
VIL	Input Low Voltage		VSS - 0.3		0.3 x VDD	V
IIH	Input High Current	VDD = VIN = 3.465V			5	μΑ
IIL	Input Low Current	VDD = 3.465V, VIN = 0V	-150			μΑ

## **AC Electrical Characteristics**

 $\label{VDD} \begin{array}{l} VDD = VDDO^{1\!\!/_2} = 3.3V \pm 5\% \mbox{ or } 2.5V \pm 5\% \\ VDD = 3.3V \pm 5\%, \mbox{ VDDO}^{1\!\!/_2} = 3.3V \pm 5\% \mbox{ or } 2.5V \pm 5\% \\ TA = -40^\circ C \mbox{ to } +85^\circ C \end{array}$ 

Symbol	Parameter	Condition	Min.	Тур.	Max.	Units
FIN	Input Frequency	Reference Input		50		MHz
FOUT	Output Frequency	LVPECL		200 x 2		MHz
TR/TF	Output Rise/Fall time <sup>3</sup>	LVPECL ouput	85	135	350	ps
ODC	Output Duty Cycle	<400MHz output frequencies	48	50	52	%
Tpd	Input-to-Input Propagation Delay	ZDB mode Generator/Bypass mode	-100	4	100	ps ns
Tskew	Output-to-Output Skew	Notes 4, 5 Same output bank			50	ps
Tlock	PLL Lock Time			5	20	ms
Tjit(Ø)	RMS Phase Noise	Notes 6, 7 Integration range (12kHz-20MHz)		78		fs

## **Temperature Specifications**

Parameter	Sym.	Min.	Тур.	Max.	Units	Conditions
Temperature Ranges						
Ambient Temperature Range	Та	-40		+85	°C	
Lead Temperature				+260	°C	Soldering, 20s
Case Temperature				+115	°C	
Storage Temperature Range	Ts	-65		+150	°C	
Package Thermal Resistances (Note 8)						
Junction Thermal Resistance, 4 x 4 VQFN-24Ld	Tja		25		°C/W	Still-Air

#### Notes:

3. See Figure 'All Outputs Rise/Fall Time'

4. Output-to-output skew is defined as skew between outputs at the same supply voltage and with equal load conditions. It is measured at the output differential crossing points.

5. Output-to-output skew is only defined for outputs in the same PLL bank [A:B, C:D] with the same output logic type setting.

6. All phase noise measurements were taken with an Agilent 5052B phase noise system.

7. Reference frequency generated using R+S SMA100A (option 02). When using an external

reference input, use a low phase noise source as the phase noise will follow the input source phase noise up to about 1MHz.

8. Package thermal resistance assumes the exposed pad is soldered (or equivalent) to the device's most negative potential on the PCB.

#### **Application Information**

#### **Input Reference**

When operating with a crystal input reference, do not apply a switching signal to REF\_IN.

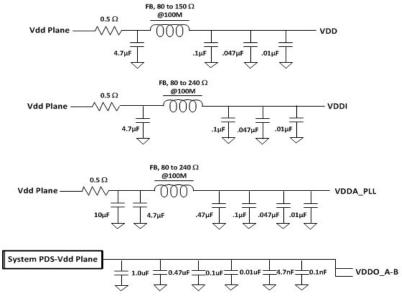
**Power Supply Filtering Recommendations** 

#### **Output Traces**

Design the traces for the output signals according to the output logic requirements. If LVCMOS is unterminated, add a 30 Ohms resistor in series with the output, as close as possible to the output pin and start a 50 Ohms trace on the other side of the resistor.

For differential traces you can either use a differential design or two separate 50 Ohms traces. For EMI reasons, it is better to use a balanced differential design.

LVDS can be AC coupled or DC coupled to its termination.



#### Figure 1. Recommended Power Supply Filtering

- Use the power supply filtering shown in above figure for VDD, VDDA\_PLL, VDDI.
- Connect the VDDO pins directly to the VDD power plane.
- Connect all VSS pins directly to the ground power plane.
- Recommended ferrite bead properties are 80 Ohms to 240 Ohms @100MHz impedance and >250mA saturation current.
- To improve power supply filtering beyond what a ferrite bead can provide, Microchip's Ripple Blocker<sup>TM</sup> provides a solution. MIC94300 or MIC94310 are recommended parts. The filter circuit with Ripple Blocker is shown in below figure and can be used for any of the above VDD sections.
- Do not use Y5V or Z5U capacitors.

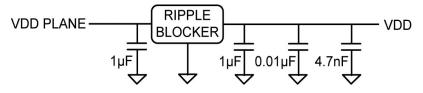


Figure 2. Power Supply Filtering with Ripple Blocker

#### **Timing Diagrams**

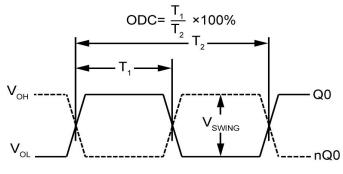


Figure 3. Duty Cycle Timing

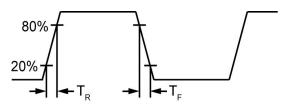


Figure 4. All Outputs Rise/Fall Time

#### **RMS Phase/Noise/Jitter**

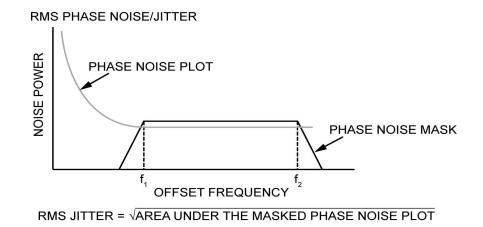


Figure 5. RMS Phase/Noise/Jitter

# **Output Termination**

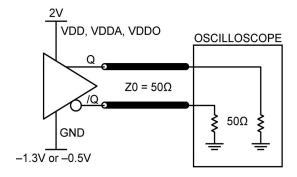
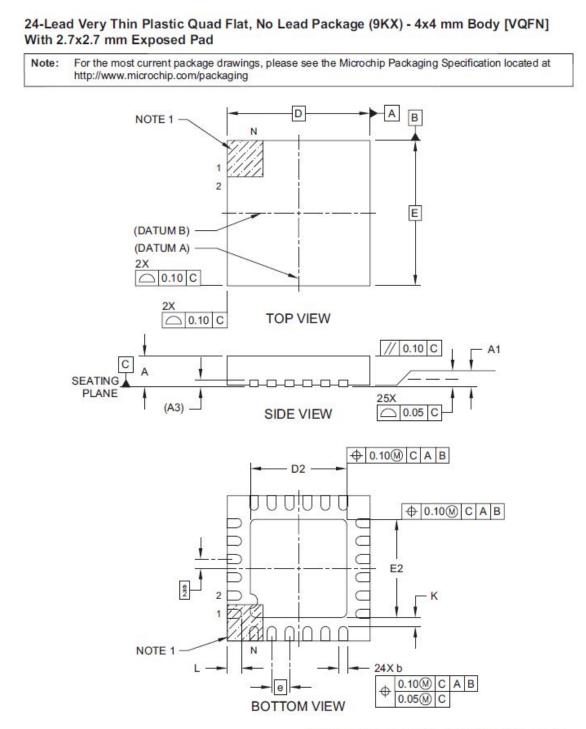


Figure 6. LVPECL Output Load and Test Circuit

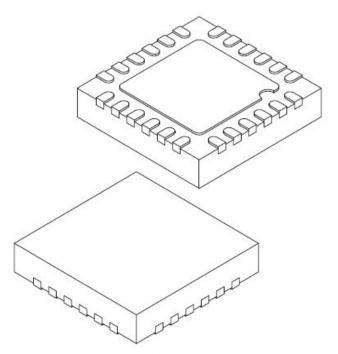
#### **Packaging Information**



Microchip Technology Drawing C04-428 Rev A Sheet 1 of 2

#### 24-Lead Very Thin Plastic Quad Flat, No Lead Package (9KX) - 4x4 mm Body [VQFN] With 2.7x2.7 mm Exposed Pad

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	MILLIMETERS			
Dimens	ion Limits	MIN	NOM	MAX	
Number of Terminals	N		24		
Pitch	e		0.50 BSC		
Overall Height	A	0.80	0.85	0.90	
Standoff	A1	0.00	0.02	0.05	
Terminal Thickness	A3	0.20 REF			
Overall Length	D		4.00 BSC		
Exposed Pad Length	D2	2.60	2.70	2.80	
Overall Width	E		4.00 BSC		
Exposed Pad Width	E2	2.60	2.70	2.80	
Terminal Width	b	0.18	0.25	0.30	
Terminal Length	L	0.35	0.40	0.45	
Terminal-to-Exposed-Pad	К		0.25 REF		

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. Package is saw singulated

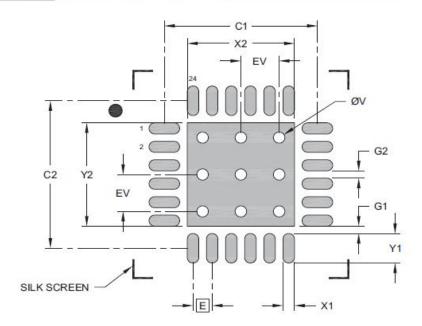
3. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances. REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-428 Rev A Sheet 2 of 2

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#### RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension	MIN	NOM	MAX	
Contact Pitch	E		0.50 BSC	
Optional Center Pad Width	X2			2.80
Optional Center Pad Length	Y2			2.80
Contact Pad Spacing	C1		4.00	
Contact Pad Spacing	C2		4.00	
Contact Pad Width (X24)	X1			0.30
Contact Pad Length (X24)	Y1			0.80
Contact Pad to Center Pad (X24)	G1	0.20		
Contact Pad to Contact Pad (X20)	G2	0.20		
Thermal Via Diameter	V		0.30	
Thermal Via Pitch	EV		1.00	

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

Microchip Technology Drawing C04-2428 Rev A

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